1. (Previously presented) In a semiconductor imaging chip having a plurality of active pixel sensors arranged in an array of rows and columns, each active pixel sensor having a respective internal offset voltage output superimposed on its respective active pixel sensor output, and wherein a current row of said array has an access line shared with a reset line of a previous row of said array to form a shared access/reset line which simultaneously accesses said current row and resets said previous row, a method for canceling the internal offset voltage appearing at the output of a given active pixel sensor on said current row to form a corrected output, said method comprising:

accessing a first row of said array to obtain a first sample of said given active pixel sensor output;

storing said first sample of said given active pixel sensor output of said first row of said array;

accessing a second row of said array, said first row of said array being the previous row to said second row of said array; and thereafter,

accessing said first row of said array a second time to obtain a second sample of said given active pixel sensor output;

storing said second sample of said given active pixel sensor output of said first row of said array; and

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